



Docket No.: M4065.0210/P210-A  
(PATENT)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

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In re Patent Application of:  
Sam Yang et al.

Application No.: 10/002,176

Confirmation No.: 3795

Filed: December 5, 2001

Art Unit: 2814

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For: METHOD OF FORMING A CAPACITOR  
FOR A SEMICONDUCTOR DEVICE

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Examiner: H. B. Trinh

**FIRST PRELIMINARY AMENDMENT**

MS Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

**INTRODUCTORY COMMENTS**

Prior to examination on the merits, please amend the above-identified U.S. patent application as follows:

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2 of this paper.

Remarks begin on page 9 of this paper.